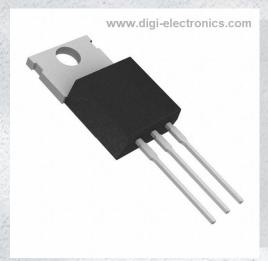


MJE15031G Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number MJE15031G-DG

Manufacturer onsemi

Manufacturer Product Number MJE15031G

Description TRANS PNP 150V 8A TO220

Detailed Description Bipolar (BJT) Transistor PNP 150 V 8 A 30MHz 50 W

Through Hole TO-220



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MJE15031G	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	8 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
150 V	500mV @ 100mA, 1A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100μΑ	20 @ 4A, 2V
Power - Max:	Frequency - Transition:
50 W	30MHz
Operating Temperature:	Mounting Type:
-65°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-220-3	TO-220
Base Product Number:	
MJE15031	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	Not Applicable
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0075	



Complementary Silicon Plastic Power Transistors MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

These devices are designed for use as high-frequency drivers in audio amplifiers.

Features

- High Current Gain Bandwidth Product
- TO-220 Compact Package
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

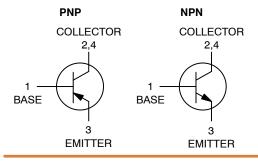
Rating	Symbol	Value	Unit
Collector-Emitter Voltage MJE15028G, MJE15029G MJE15030G, MJE15031G	V _{CEO}	120 150	Vdc
Collector-Base Voltage MJE15028G, MJE15029G MJE15030G, MJE15031G	V _{CB}	120 150	Vdc
Emitter-Base Voltage	V _{EB}	5.0	Vdc
Collector Current - Continuous	I _C	8.0	Adc
Collector Current - Peak	I _{CM}	16	Adc
Base Current	Ι _Β	2.0	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	50 0.40	W W/°C
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	2.0 0.016	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

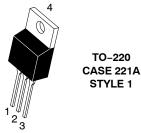
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

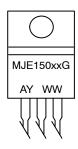
Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.5	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W

8 AMPERE POWER TRANSISTORS COMPLEMENTARY SILICON 120-150 VOLTS, 50 WATTS





MARKING DIAGRAM



MJE150xx = Device Code

x = 28, 29, 30, or 31 = Assembly Location

A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

1

^{*}For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 1) (I _C = 10 mAdc, I _B = 0) MJE15028, MJE15029 MJE15030, MJE15031	V _{CEO(sus)}	120 150	- -	Vdc
Collector Cutoff Current $(V_{CE} = 120 \text{ Vdc}, I_B = 0)$ MJE15028, MJE15029 $(V_{CE} = 150 \text{ Vdc}, I_B = 0)$ MJE15030, MJE15031	ICEO	-	0.1 0.1	mAdc
Collector Cutoff Current (V _{CB} = 120 Vdc, I _E = 0) MJE15028, MJE15029 (V _{CB} = 150 Vdc, I _E = 0) MJE15030, MJE15031	Ісво	-	10 10	μAdc
Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0)	I _{EBO}	-	10	μAdc
ON CHARACTERISTICS (Note 1)				
DC Current Gain	h _{FE}	40 40 40 20	- - - -	-
DC Current Gain Linearity (V _{CE} From 2.0 V to 20 V, I _C From 0.1 A to 3 A) (NPN to PNP)	h _{FE}		yp 2 3	
Collector-Emitter Saturation Voltage (I _C = 1.0 Adc, I _B = 0.1 Adc)	V _{CE(sat)}	-	0.5	Vdc
Base-Emitter On Voltage (I _C = 1.0 Adc, V _{CE} = 2.0 Vdc)	V _{BE(on)}	-	1.0	Vdc
DYNAMIC CHARACTERISTICS	<u>.</u>			
Current Gain – Bandwidth Product (Note 2) (I _C = 500 mAdc, V _{CE} = 10 Vdc, f _{test} = 10 MHz)	f _T	30	-	MHz
	•			

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

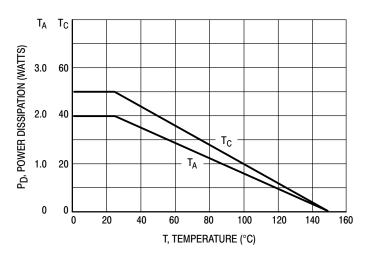


Figure 1. Power Derating

^{2.} $f_T = |h_{fe}| \cdot f_{test}$.

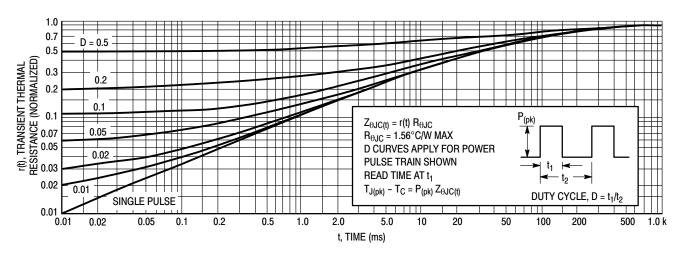


Figure 2. Thermal Response

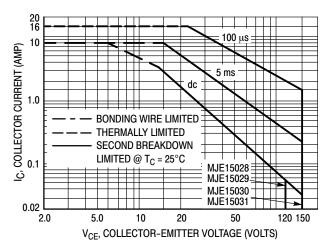


Figure 3. Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation then the curves indicate.

The data of Figures 3 and 4 is based on $T_{J(pk)} = 150^{\circ} C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150^{\circ} C$. $T_{J(pk)}$ may be calculated from the data in Figure 2. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

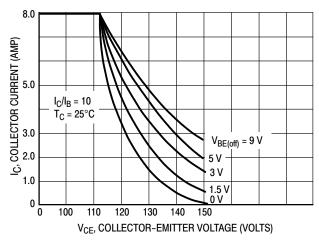


Figure 4. Reverse-Bias Switching Safe Operating Area

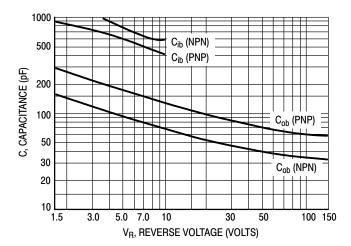
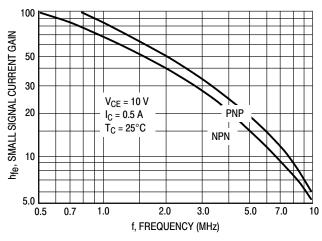


Figure 5. Capacitances



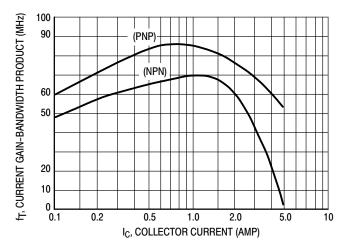
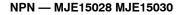
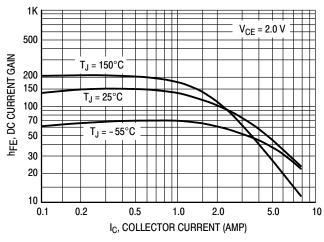


Figure 6. Small-Signal Current Gain

Figure 7. Current Gain-Bandwidth Product





PNP — MJE15029 MJE15031

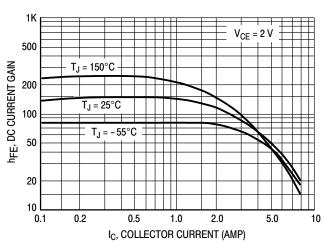
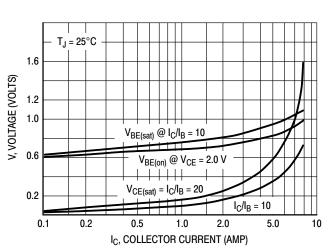
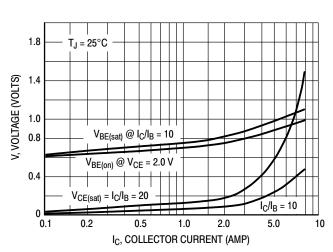


Figure 8. DC Current Gain

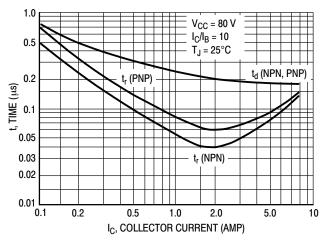


NPN



PNP

Figure 9. "On" Voltage



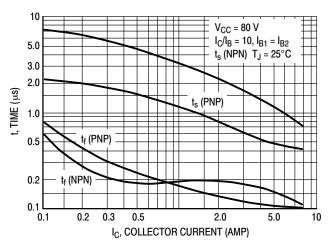


Figure 10. Turn-On Times

Figure 11. Turn-Off Times

ORDERING INFORMATION

Device	Package	Shipping
MJE15028G	TO-220 (Pb-Free)	50 Units / Rail
MJE15029G	TO-220 (Pb-Free)	50 Units / Rail
MJE15030G	TO-220 (Pb-Free)	50 Units / Rail
MJE15031G	TO-220 (Pb-Free)	50 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D.</u>



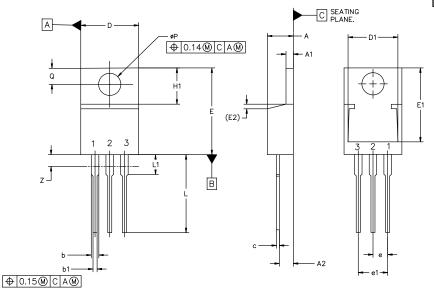
MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



TO-220-3 10.10x15.12x4.45, 2.54P CASE 221A **ISSUE AL**

DATE 05 FEB 2025



MILLIMETERS							
DIM	MIN	MIN NOM MAX					
Α	4.07	4.45	4.83				
A1	1.15	1.28	1.41				
A2	2.04	2.42	2.79				
b	1.15	1.34	1.52				
b1	0.64	0.80	0.96				
С	0.36	0.49	0.61				
D	9.66	10.10	10.53				
D1	8.43	8.63	8.83				
E	14.48	15.12	15.75				
E1	12.58	12.78	12.98				
E2	1.27 REF						

MILLIMETERS						
DIM	MIN	NOM	MAX			
е	2.42	2.54	2.66			
e1	4.83	5.08	5.33			
H1	5.97	6.22	6.47			
L	12.70	13.49	14.27			
L1	2.80	3.45	4.10			
Q	2.54	2.79	3.04			
ØΡ	3.60	3.85	4.09			
Z		-,	3.48			

NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	BASE	PIN 1.	BASE	PIN 1.	CATHODE	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	EMITTER	2.	ANODE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	COLLECTOR	3.	GATE	3.	GATE
4.	COLLECTOR	4.	EMITTER	4.	ANODE	4.	MAIN TERMINAL 2
STYLE 5:		STYLE 6:		STYLE 7:		STYLE 8:	
PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	CATHODE	PIN 1.	CATHODE
2.	DRAIN	2.	CATHODE	2.	ANODE	2.	ANODE
3.	SOURCE	3.	ANODE	3.	CATHODE	3.	EXTERNAL TRIP/DELAY
4.	DRAIN	4.	CATHODE	4.	ANODE	4.	ANODE
STYLE 9:		STYLE 10:		STYLE 11:		STYLE 12	:
PIN 1.	GATE	PIN 1.	GATE	PIN 1.	DRAIN	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	SOURCE	2.	SOURCE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	DRAIN	3.	GATE	3.	GATE
4.	COLLECTOR	4.	SOURCE	4.	SOURCE	4.	NOT CONNECTED

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DESCRIPTION:	TO-220-3 10.10x15.12x4.45, 2.54P		PAGE 1 OF 1	

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